MMBT6428LT1G, MMBT6429LT1G, NSVMMBT6429LT1G

Amplifier Transistors

NPN Silicon

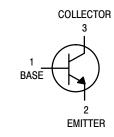
Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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Rating	Symbol	6428LT1	6429LT1	Unit
Collector-Emitter Voltage	V _{CEO}	50	45	Vdc
Collector-Base Voltage	V _{CBO}	60	55	Vdc
Emitter-Base Voltage	V _{EBO}	6.0		Vdc
Collector Current – Continuous	Ι _C	200		mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit	
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	225 1.8	mW mW/⁰C	
Derate above 25 C		1.0		
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W	
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$	PD	300	mW	
Derate above 25°C		2.4	mW/°C	
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W	
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C	

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



XXX = Specific Device Code MMBT6428LT1 – 1KM

- NSV/MMBT6429LT1 M1L
- M = Date Code*
- = Pb–Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT6428LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBT6429LT1G	SOT–23 (Pb–Free)	3000 Tape & Reel
NSVMMBT6429LT1G	SOT–23 (Pb–Free)	3000 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteris	tic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	MMBT6428 MMBT6429 / NSVMMBT6429	V _{(BR)CEO}	50 45		Vdc
Collector – Base Breakdown Voltage $(I_C = 0.1 \text{ mAdc}, I_E = 0)$ $(I_C = 0.1 \text{ mAdc}, I_E = 0)$	MMBT6428 MMBT6429 / NSVMMBT6429	V _{(BR)CBO}	60 55		Vdc
Collector Cutoff Current (V _{CE} = 30 Vdc)		ICES	-	0.1	μAdc
Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}, I_E = 0$)		I _{CBO}	-	0.01	μAdc
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ Vdc}, I_C = 0$)		I _{EBO}	-	0.01	μAdc

ON CHARACTERISTICS

DC Current Gain		h _{FE}			-
$(I_{C} = 0.01 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	MMBT6428 MMBT6429 / NSVMMBT6429		250 500	-	
$(I_{C} = 0.1 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	MMBT6428 MMBT6429 / NSVMMBT6429		250 500	650 1250	
$(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	MMBT6428 MMBT6429 / NSVMMBT6429		250 500	-	
$(I_{C} = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	MMBT6428 MMBT6429 / NSVMMBT6429		250 500	-	
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc}$) ($I_C = 100 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$)		V _{CE(sat)}	-	0.2 0.6	Vdc
Base-Emitter On Voltage (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc)		V _{BE(on)}	0.56	0.66	Vdc

SMALL-SIGNAL CHARACTERISTICS

Current-Gain – Bandwidth Product ($I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	100	700	MHz
Output Capacitance (V_{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	-	3.0	pF
Input Capacitance ($V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz}$)	C _{ibo}	-	8.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

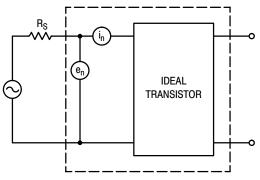


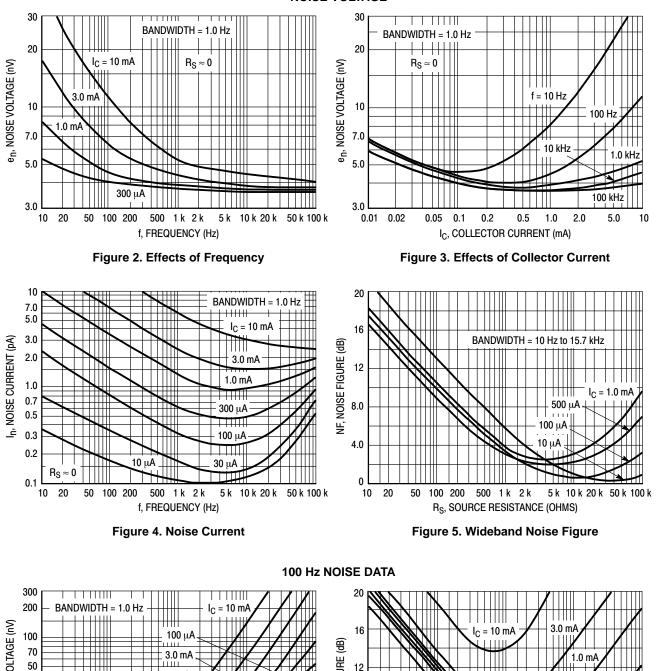
Figure 1. Transistor Noise Model

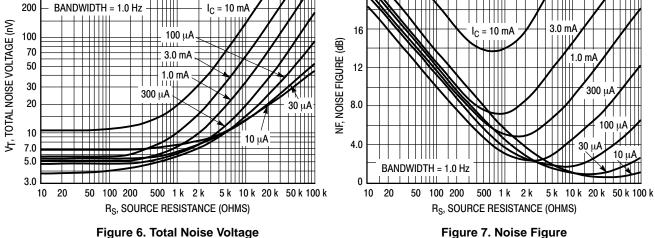
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NOISE CHARACTERISTICS

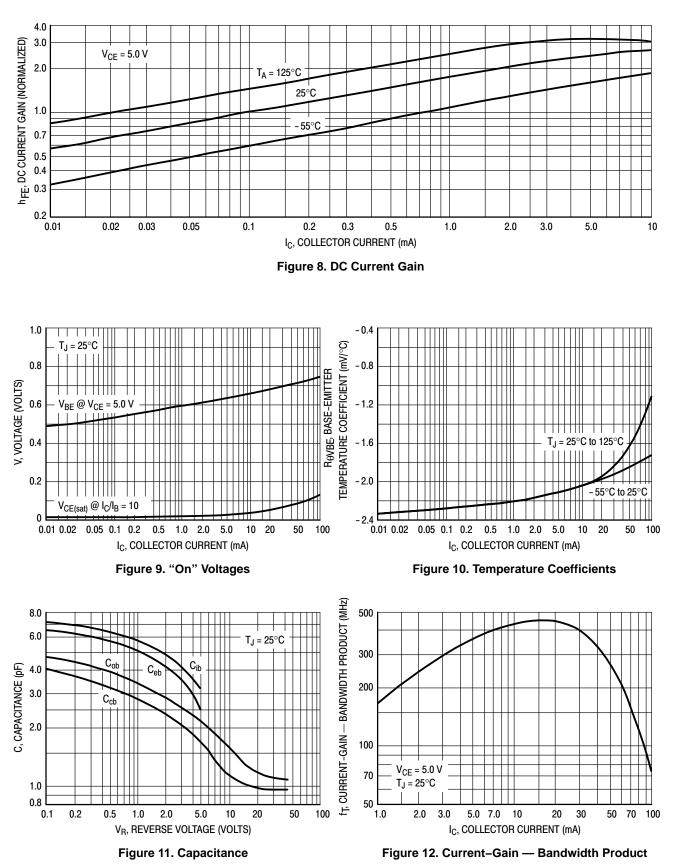
 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

NOISE VOLTAGE





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